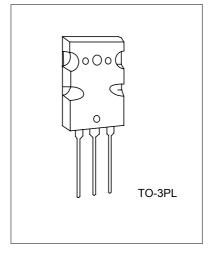
UTC 2SC5200 NPN EPITAXIAL SILICON TRANSISTOR

POWER AMPLIFIER APPLICATIONS

FEATURES

- * Recommended for 100W High Fidelity Audio Frequency Amplifier Output Stage.
- * Complementary to UTC 2SA1943



*Pb-free plating product number: 2SC5200L

ABSOLUTE MAXIMUM RATINGS (Tc = 25°C)

| , DOOLOTE IVII VAIIVIOIVITA ATTIVOC | (10 - 200) | | |
|--------------------------------------|----------------|-----------|----------------------|
| PARAMETER | SYMBOL | RATINGS | UNIT |
| Collector-Base Voltage | V_{CBO} | 230 | V |
| Collector-Emitter Voltage | V_{CEO} | 230 | V |
| Emitter-Base Voltage | V_{EBO} | 5 | V |
| Collector Current | Ic | 15 | Α |
| Base Current | I _B | 1.5 | Α |
| Collector Power Dissipation (Tc=25℃) | Pc | 150 | W |
| Junction Temperature | TJ | 150 | $^{\circ}\mathbb{C}$ |
| Storage Temperature Range | Tstg | -55 ~ 150 | $^{\circ}\mathbb{C}$ |

ELECTRICAL CHARACTERISTICS (Tc=25°C)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------------------------------|-----------------------|--|-----|------|-----|---------|
| Collector-Emitter Breakdown Voltage | V _{(BR) CEO} | I_C = 50mA, I_B =0 | 230 | | | V |
| Collector-Emitter Saturation Voltage | | I _C = 8A, I _B = 0.8A | | 0.40 | 3.0 | V |
| Base -Emitter Voltage | V_{BE} | V_{CE} = 5V, I_{C} = 7A | | 1.0 | 1.5 | V |
| Collector Cut-off Current | I _{CBO} | $V_{CB} = 230V, I_{E} = 0$ | | | 5.0 | μA |
| Emitter Cut-off Current | I _{EBO} | V_{EB} = 5V, I_{C} =0 | | | 5.0 | μA |
| DC Current Gain | h _{FE1} | V _{CE} = 5V, I _C = 1A | 55 | | 160 | |
| | h _{FE2} | V_{CE} = 5V, I_{C} = 7A | 35 | 60 | | |
| Transition Frequency | fτ | V _{CE} = 5V, I _C = 1A | | 30 | | MHz |
| Collector Output Capacitance | Cob | V _{CB} = 10V, I _E =0, f=1MHz | | 200 | | pF |

Note: hfe (1) Classification, R : $55 \sim 110$, O : $80 \sim 160$

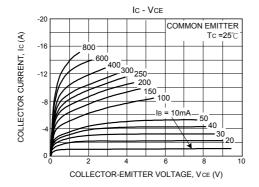
CLASSIFICATION OF HFE1

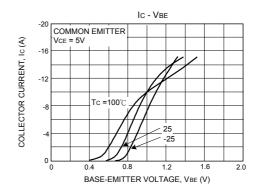
| RANK | R | 0 |
|-------|----------|----------|
| Range | 55 ~ 110 | 80 ~ 160 |

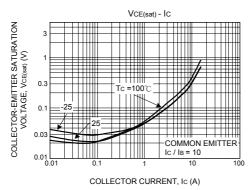
UTC UNISONIC TECHNOLOGIES CO. LTD

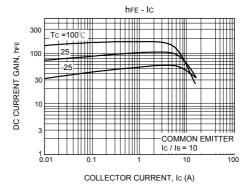
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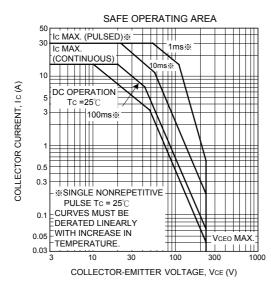
TYPICAL CHARACTERISTICS











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UTC 2SC5200 NPN EPITAXIAL SILICON TRANSISTOR

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